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Hyperfast Rectifier, 30 A FRED Pt[®] G5



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	30 A				
V _R	600 V				
V _F at I _F at 125 °C	1.15 V				
t _{rr} (typ.)	25				
I _{FSM}	330				
T _J max.	175 °C				
Package	TO-247AD 3L				
Circuit configuration	Single				

FEATURES

- Hyperfast and optimized Qrr
- Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature FREE
- Polyimide passivation
- AEC-Q101 qualified meets JESD 201 class 1A whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters. This device is specifically designed to improve efficiency of high speed LLC output rectification stages of EV / HEV on-board battery chargers

MECHANICAL DATA

Case: TO-247AD 3L Molding compound meets UL 94 V-0 flammability rating Terminal: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Repetitive peak reverse voltage	V _{RRM}		600	V				
Average rectified forward current	I _{F(AV)}	T _C = 123 °C, D = 0.50	30					
Non-repetitive peak surge current	I _{FSM}	T_{C} = 25 °C, t_{p} = 10 ms, sine wave, both anodes, (1) and (3) connected	330	А				
Repetitive peak forward current	I _{FRM}	T _C = 123 °C, D = 0.50, f = 20 kHz	60					
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C				

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	R SYMBOL TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	600	-	-			
Forward voltage	V	I _F = 30 A	-	1.3	1.6	V		
Forward voltage	V _F	I _F = 30 A, T _J = 125 °C	-	1.15	-			
Reverse leakage current	I	$V_{R} = V_{R}$ rated	-	-	20	μA		
neverse leakage current	IR	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μΑ		
Junction capacitance	CT	V _R = 200 V	-	36	-	pF		
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH		

g RoHS

COMPLIANT

HALOGEN

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VS-A5PH3006LHN3



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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25 \text{ °C}$ unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS			TYP.	MAX.	UNITS	
		$I_F = 1.0 \text{ A}, \text{ d}_F/\text{d}t = 100$) A/µs, V _R = 30 V	-	25	-		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	41	-	ns	
		T _J = 125 °C		-	58	-		
Peak recovery current		T _J = 25 °C	$I_F = 20 \text{ A},$	-	19	-	А	
Feak recovery current	I _{RRM}	T _J = 125 °C	dI _F /dt = 1000 A/μs, V _R = 400 V	-	32	-	A	
	Q _{rr} -	T _J = 25 °C		-	419	-	nC	
Reverse recovery charge		T _J = 125 °C		-	1176	-	nc	
		T _J = 25 °C		-	46	-		
Reverse recovery time	t _{rr}	T _J = 125 °C		-	65	-	ns	
De als vera assert		T _J = 25 °C	I _F = 30 A, dI _F /dt = 1000 A/μs, V _B = 400 V	-	21	-	•	
Peak recovery current	I _{RRM}	T _J = 125 °C		-	36	-	A	
5	0	T _J = 25 °C		-	550	-		
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	1560	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction-to-case	R _{thJC}		-	-	1.1	°C/W		
Weight			-	5.5	-	g		
Weight			-	0.2	-	oz.		
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C		
Marking device		Case style: TO-247AD 3L		A5PH3	8006LH			

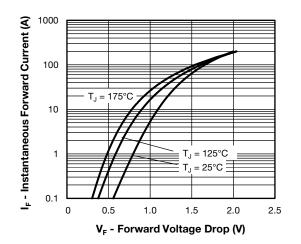


Fig. 1 - Forward Voltage Drop Characteristics

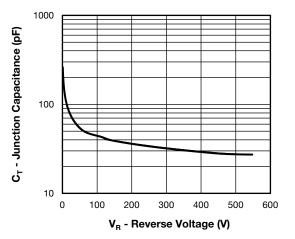
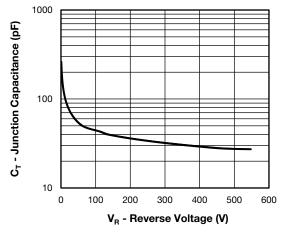


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage





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Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

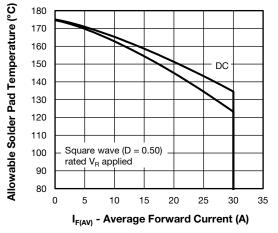


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

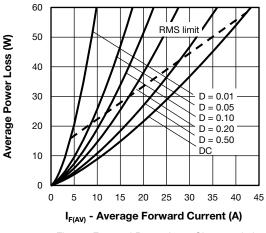


Fig. 5 - Forward Power Loss Characteristics

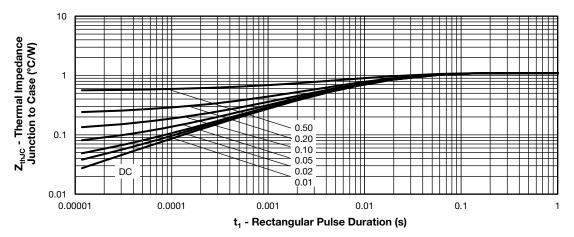


Fig. 6 - Transient Thermal Impedance, Junction to Case

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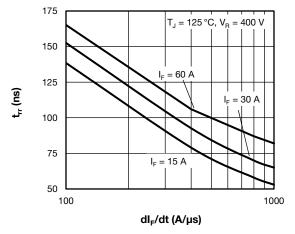


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

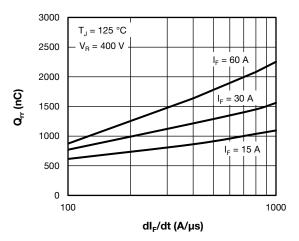


Fig. 8 - Typical Reverse Recovery Charge vs. dl_F/dt

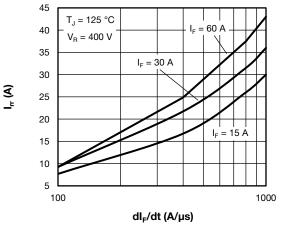


Fig. 9 - Typical Reverse Recovery Current vs. dl_F/dt

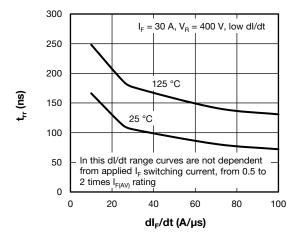
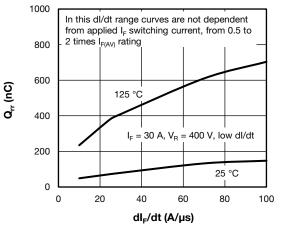


Fig. 10 - Typical Reverse Recovery Time vs. dl_F/dt





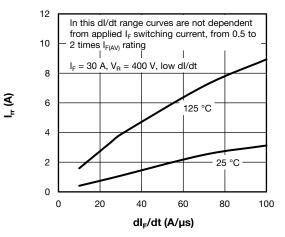


Fig. 12 - Typical Reverse Recovery Current vs. dl_F/dt

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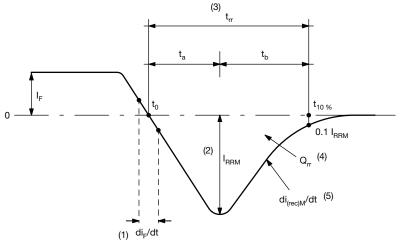


Fig. 13 - Reverse Recovery Waveform and Definitions

Notes

- $^{(1)}~di_{\text{F}}/dt$ rate of change of current through zero crossing
- $^{(2)}\ \ I_{RRM}$ peak reverse recovery current
- ⁽³⁾ t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F, to point $t_{10\%}$, 0.1 I_{RRM}
- $^{(4)}$ $\, \dot{Q}_{rr}$ area under curve defined by t_0 and $t_{10~\%}$

$$Q_{rr} = \int_{t_0}^{t_{10\%}} I(t) dt$$

 $^{(5)}$ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

ORDERING INFORMATION TABLE

Device code	VS-	Α	5	Р	н	30	06	L	Н	N3
	1	2	3	4	5	6	7	8	9	10
	1 - 2 - 3 - 4 - 5 - 6 - 7 - 8 -	 Circ A = FRI P = Pro H = Cur Volt 	cuit cont single of ED Pt [®] of TO-247 cess typ hyperfa rent rati	' packag	n anodes ge very = 30 A) = 600 V)	i	D)			
	9 - 10 -	Env	ironmer	101 qua ntal digit en-free,	:	complia	nt, and	totally l	ead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-A5PH3006LHN3	25	500	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimensions		www.vishay.com/doc?95626			
Part marking information		www.vishay.com/doc?95007			
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TO-247AD 3L

DIMENSIONS in millimeters and inches



View B

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
с	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

(2, 52, 51) (4) Section C - C, D - D, E - E

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	5 BSC	
ØК	0.2	254	0.0	010	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØР	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51	BSC	0.217	' BSC	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

- ⁽³⁾ Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- ⁽⁵⁾ Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- ⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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 1
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